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### Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

### Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

Product Status	Active
Core Processor	ARM1136JF-S
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	532MHz
Co-Processors/DSP	Multimedia; GPU, IPU, MPEG-4, VFP
RAM Controllers	DDR
Graphics Acceleration	Yes
Display & Interface Controllers	Keyboard, Keypad, LCD
Ethernet	-
SATA	-
USB	USB 2.0 (3)
Voltage - I/O	1.8V, 2.0V, 2.5V, 2.7V, 3.0V
Operating Temperature	-20°C ~ 70°C (TA)
Security Features	Random Number Generator, RTIC, Secure Fusebox, Secure JTAG, Secure Memory
Package / Case	457-LFBGA
Supplier Device Package	457-LFBGA (14x14)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx31dvkn5d">https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx31dvkn5d</a>

## 1.3 Block Diagram

Figure 1 shows the MCIMX31 simplified interface block diagram.

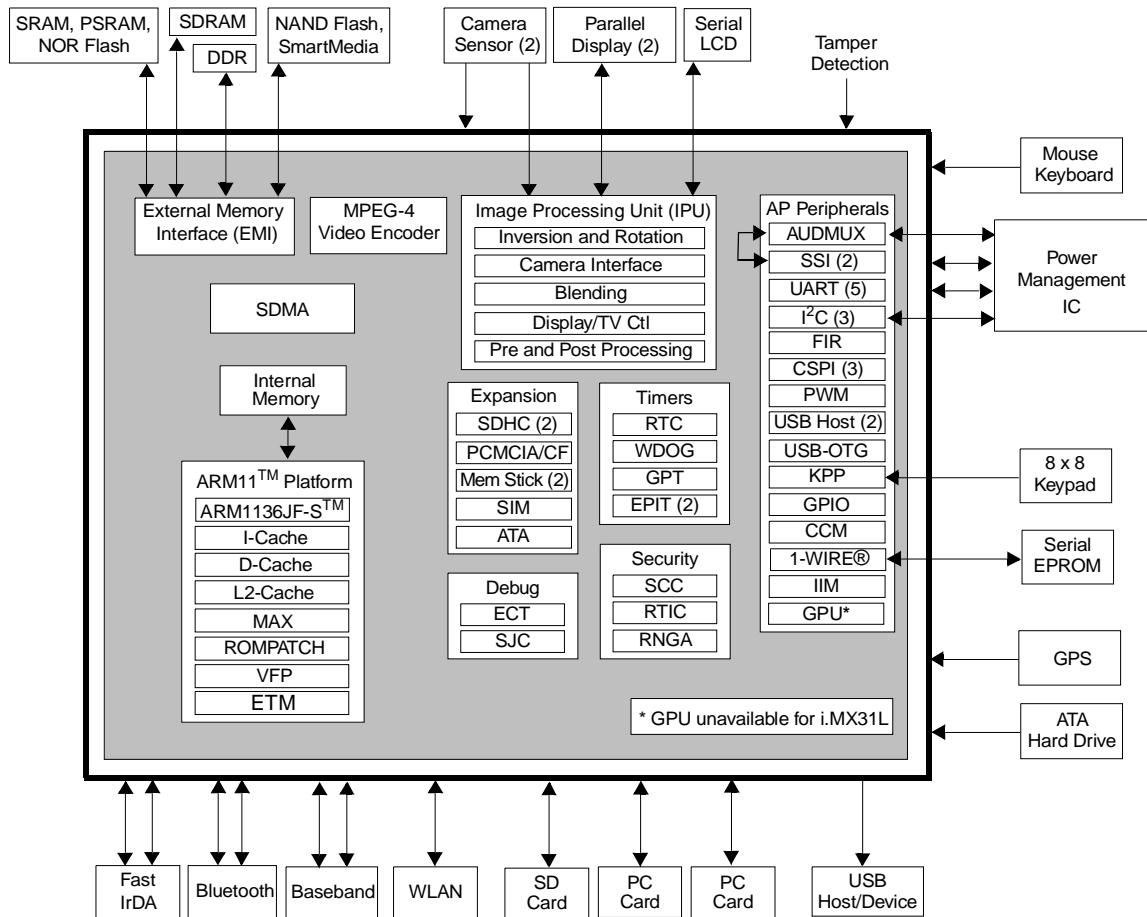


Figure 1. MCIMX31 Simplified Interface Block Diagram

## 2 Functional Description and Application Information

### 2.1 ARM11 Microprocessor Core

The CPU of the MCIMX31 is the ARM1136JF-S core based on the ARM v6 architecture. It supports the ARM Thumb<sup>®</sup> instruction sets, features Jazelle<sup>®</sup> technology (which enables direct execution of Java byte codes), and a range of SIMD DSP instructions that operate on 16-bit or 8-bit data values in 32-bit registers.

The ARM1136JF-S processor core features:

- Integer unit with integral EmbeddedICE<sup>™</sup> logic
- Eight-stage pipeline
- Branch prediction with return stack
- Low-interrupt latency

**Table 3. Digital and Analog Modules (continued)**

<b>Block Mnemonic</b>	<b>Block Name</b>	<b>Functional Grouping</b>	<b>Brief Description</b>	<b>Section/ Page</b>
Fusebox	Fusebox	ROM	The Fusebox is a ROM that is factory configured by Freescale.	<a href="#">4.3.12/53</a> See also <a href="#">Table 11</a>
GPIO	General Purpose I/O Module	Pins	The GPIO provides several groups of 32-bit bidirectional, general purpose I/O. This peripheral provides dedicated general-purpose signals that can be configured as either inputs or outputs.	—
GPT	General Purpose Timer	Timer Peripheral	The GPT is a multipurpose module used to measure intervals or generate periodic output.	—
GPU	Graphics Processing Unit	Multimedia Peripheral	The GPU provides hardware acceleration for 2D and 3D graphics algorithms.	—
I <sup>2</sup> C	Inter IC Communication	Connectivity Peripheral	The I <sup>2</sup> C provides serial interface for controlling the Sensor Interface and other external devices. Data rates of up to 100 Kbits/s are supported.	<a href="#">4.3.13/54</a>
IIM	IC Identification Module	ID	The IIM provides an interface for reading device identification.	—
IPU	Image Processing Unit	Multimedia Peripheral	The IPU processes video and graphics functions in the MCIMX31 and interfaces to video, still image sensors, and displays.	<a href="#">4.3.14/55</a> , <a href="#">4.3.15/57</a>
KPP	Keypad Port	Connectivity Peripheral	The KPP is used for keypad matrix scanning or as a general purpose I/O. This peripheral simplifies the software task of scanning a keypad matrix.	—
MPEG-4	MPEG-4 Video Encoder	Multimedia Peripherals	The MPEG-4 encoder accelerates video compression, following the MPEG-4 standard	—
MSHC	Memory Stick Host Controller	Connectivity Peripheral	The MSHC is placed in between the AIPS and the customer memory stick to support data transfer from the MCIMX31 to the customer memory stick.	<a href="#">4.3.16/82</a>
PADIO	Pads I/O	Buffers and Drivers	The PADIO serves as the interface between the internal modules and the device's external connections.	<a href="#">4.3.1/20</a>
PCMCIA	PCM	Connectivity Peripheral	The PCMCIA Host Adapter provides the control logic for PCMCIA socket interfaces.	<a href="#">4.3.17/84</a>
PWM	Pulse-Width Modulator	Timer Peripheral	The PWM has a 16-bit counter and is optimized to generate sound from stored sample audio images. It can also generate tones.	<a href="#">4.3.18/86</a>
RNGA	Random Number Generator Accelerator	Security	The RNGA module is a digital integrated circuit capable of generating 32-bit random numbers. It is designed to comply with FIPS-140 standards for randomness and non-determinism.	—
RTC	Real Time Clock	Timer Peripheral	The RTC module provides a current stamp of seconds, minutes, hours, and days. Alarm and timer functions are also available for programming. The RTC supports dates from the year 1980 to 2050.	—
RTIC	Run-Time Integrity Checkers	Security	The RTIC ensures the integrity of the peripheral memory contents and assists with boot authentication.	—

**Table 11. Fusebox Supply Current Parameters**

Ref. Num	Description	Symbol	Minimum	Typical	Maximum	Units
1	eFuse Program Current. <sup>1</sup> Current to program one eFuse bit: efuse_pgm = 3.0 V	I <sub>program</sub>	—	35	60	mA
2	eFuse Read Current <sup>2</sup> Current to read an 8-bit eFuse word vdd_fusebox = 1.875 V	I <sub>read</sub>	—	5	8	mA

<sup>1</sup> The current I<sub>program</sub> is during program time (t<sub>program</sub>).

<sup>2</sup> The current I<sub>read</sub> is present for approximately 50 ns of the read access to the 8-bit word, and only applies to Silicon Rev. 1.2 and previous.

**Table 29. CSPI Interface Timing Parameters**

ID	Parameter	Symbol	Min	Max	Units
CS1	SCLK Cycle Time	$t_{clk}$	60	—	ns
CS2	SCLK High or Low Time	$t_{SW}$	30	—	ns
CS3	SCLK Rise or Fall	$t_{RISE/FALL}$	—	7.6	ns
CS4	SSx pulse width	$t_{CSLH}$	25	—	ns
CS5	SSx Lead Time (CS setup time)	$t_{SCS}$	25	—	ns
CS6	SSx Lag Time (CS hold time)	$t_{HCS}$	25	—	ns
CS7	Data Out Setup Time	$t_{Smosi}$	5	—	ns
CS8	Data Out Hold Time	$t_{Hmosi}$	5	—	ns
CS9	Data In Setup Time	$t_{Smiso}$	6	—	ns
CS10	Data In Hold Time	$t_{Hmiso}$	5	—	ns
CS11	SPI_RDY Setup Time <sup>1</sup>	$t_{SRDY}$	—	—	ns

<sup>1</sup> SPI\_RDY is sampled internally by ipg\_clk and is asynchronous to all other CSPI signals.

## 4.3.8 DPLL Electrical Specifications

The three PLL's of the MCIMX31 (MCU, USB, and Serial PLL) are all based on same DPLL design. The characteristics provided herein apply to all of them, except where noted explicitly. The PLL characteristics are provided based on measurements done for both sources—external clock source (CKIH), and FPM (Frequency Pre-Multiplier) source.

### 4.3.8.1 Electrical Specifications

Table 30 lists the DPLL specification.

**Table 30. DPLL Specifications**

Parameter	Min	Typ	Max	Unit	Comments
CKIH frequency	15	26 <sup>1</sup>	75 <sup>2</sup>	MHz	—
CKIL frequency (Frequency Pre-multiplier (FPM) enable mode)	—	32; 32.768, 38.4	—	kHz	FPM lock time ≈ 480 μs.
Predivision factor (PD bits)	1	—	16	—	—
PLL reference frequency range after Predivider	15	—	35	MHz	$15 \leq \text{CKIH frequency/PD} \leq 35 \text{ MHz}$ $15 \leq \text{FPM output/PD} \leq 35 \text{ MHz}$
PLL output frequency range: MPLL and SPLL UPLL	52 190	—	532 240	MHz	—
Maximum allowed reference clock phase noise.	—	—	± 100	ps	—
Frequency lock time (FOL mode or non-integer MF)	—	—	398	—	Cycles of divided reference clock.

**Table 32. WEIM Bus Timing Parameters (continued)**

ID	Parameter	Min	Max	Unit
WE8	Clock rise/fall to $\overline{OE}$ Invalid	-3	3	ns
WE9	Clock rise/fall to $\overline{EB}[x]$ Valid	-3	3	ns
WE10	Clock rise/fall to $\overline{EB}[x]$ Invalid	-3	3	ns
WE11	Clock rise/fall to $\overline{LBA}$ Valid	-3	3	ns
WE12	Clock rise/fall to $\overline{LBA}$ Invalid	-3	3	ns
WE13	Clock rise/fall to Output Data Valid	-2.5	4	ns
WE14	Clock rise to Output Data Invalid	-2.5	4	ns
WE15	Input Data Valid to Clock rise, FCE=0 FCE=1	8 2.5	—	ns
WE16	Clock rise to Input Data Invalid, FCE=0 FCE=1	-2 -2	—	ns
WE17	$\overline{ECB}$ setup time, FCE=0 FCE=1	6.5 3.5	—	ns
WE18	$\overline{ECB}$ hold time, FCE=0 FCE=1	-2 2	—	ns
WE19	$\overline{DTACK}$ setup time <sup>1</sup>	0	—	ns
WE20	$\overline{DTACK}$ hold time <sup>1</sup>	4.5	—	ns
WE21	BCLK High Level Width <sup>2, 3</sup>	—	T/2 – 3	ns
WE22	BCLK Low Level Width <sup>2, 3</sup>	—	T/2 – 3	ns
WE23	BCLK Cycle time <sup>2</sup>	15	—	ns

<sup>1</sup> Applies to rising edge timing

<sup>2</sup> BCLK parameters are being measured from the 50% VDD.

<sup>3</sup> The actual cycle time is derived from the AHB bus clock frequency.

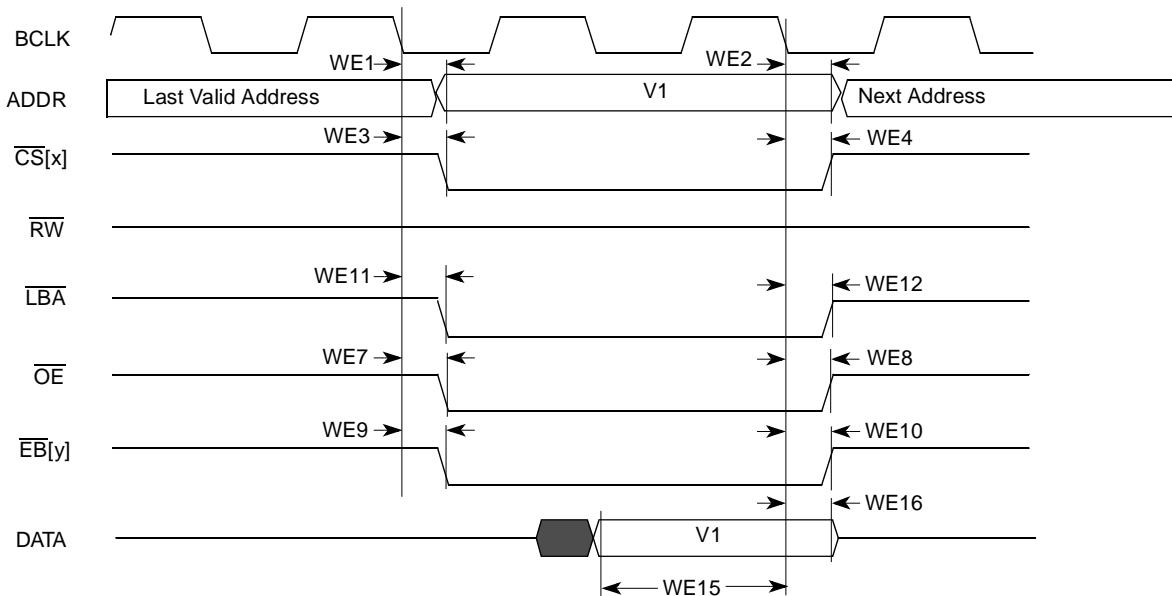
## NOTE

High is defined as 80% of signal value and low is defined as 20% of signal value.

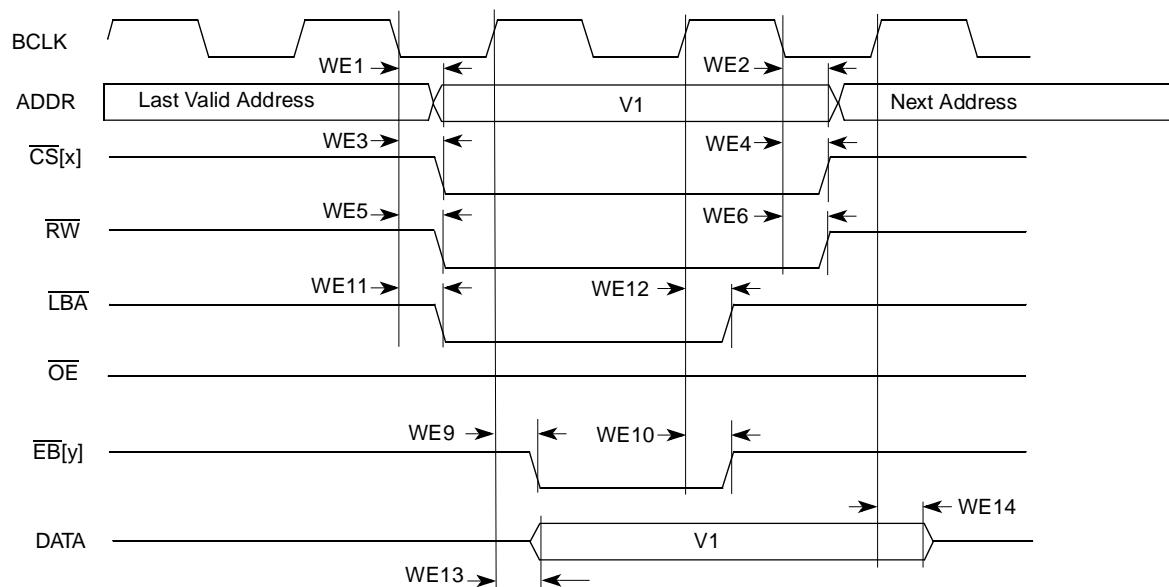
Test conditions: load capacitance, 25 pF. Recommended drive strength for all controls, address, and BCLK is Max drive.

Figure 27, Figure 28, Figure 29, Figure 30, Figure 31, and Figure 32 depict some examples of basic WEIM accesses to external memory devices with the timing parameters mentioned in Table 32 for specific control parameter settings.

## Electrical Characteristics



**Figure 27. Asynchronous Memory Timing Diagram for Read Access—WSC=1**



**Figure 28. Asynchronous Memory Timing Diagram for Write Access—WSC=1, EBWA=1, EBWN=1, LBN=1**

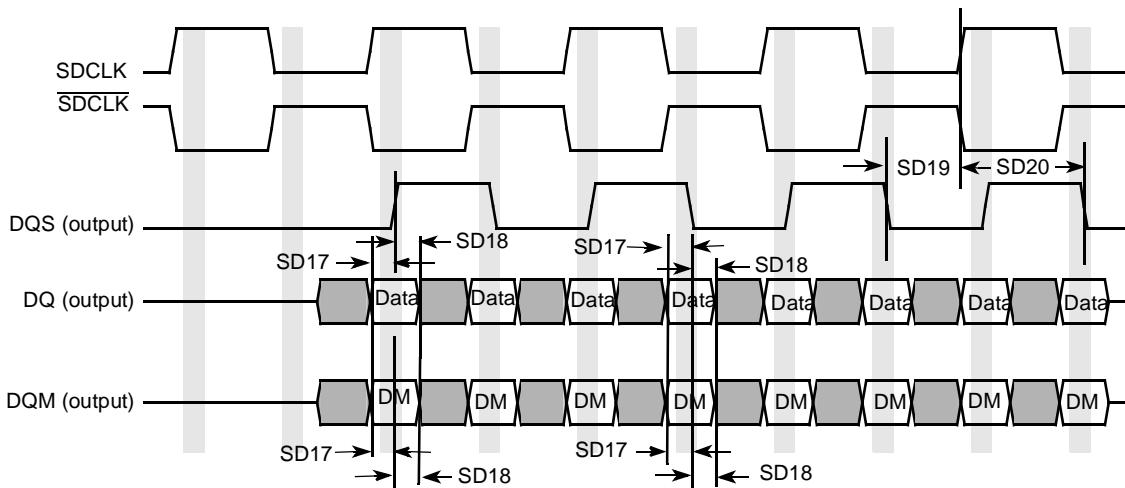


Figure 37. Mobile DDR SDRAM Write Cycle Timing Diagram

Table 37. Mobile DDR SDRAM Write Cycle Timing Parameters<sup>1</sup>

ID	Parameter	Symbol	Min	Max	Unit
SD17	DQ and DQM setup time to DQS	tDS	0.95	—	ns
SD18	DQ and DQM hold time to DQS	tDH	0.95	—	ns
SD19	Write cycle DQS falling edge to SDCLK output delay time.	tDSS	1.8	—	ns
SD20	Write cycle DQS falling edge to SDCLK output hold time.	tDSH	1.8	—	ns

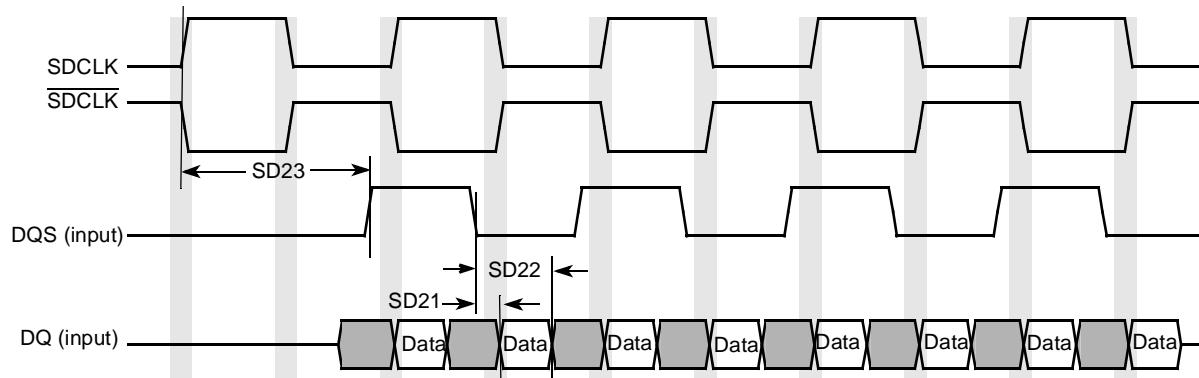
<sup>1</sup> Test condition: Measured using delay line 5 programmed as follows: ESDCDLY5[15:0] = 0x0703.

### NOTE

SDRAM CLK and DQS related parameters are being measured from the 50% point—that is, high is defined as 50% of signal value and low is defined as 50% of signal value.

The timing parameters are similar to the ones used in SDRAM data sheets—that is, Table 37 indicates SDRAM requirements. All output signals are driven by the ESDCTL at the negative edge of SDCLK and the parameters are measured at maximum memory frequency.

## Electrical Characteristics



**Figure 38. Mobile DDR SDRAM DQ versus DQS and SDCLK Read Cycle Timing Diagram**

**Table 38. Mobile DDR SDRAM Read Cycle Timing Parameters**

ID	Parameter	Symbol	Min	Max	Unit
SD21	DQS – DQ Skew (defines the Data valid window in read cycles related to DQS).	tDQSQ	—	0.85	ns
SD22	DQS DQ HOLD time from DQS	tQH	2.3	—	ns
SD23	DQS output access time from SDCLK posedge	tDQSCK	—	6.7	ns

### NOTE

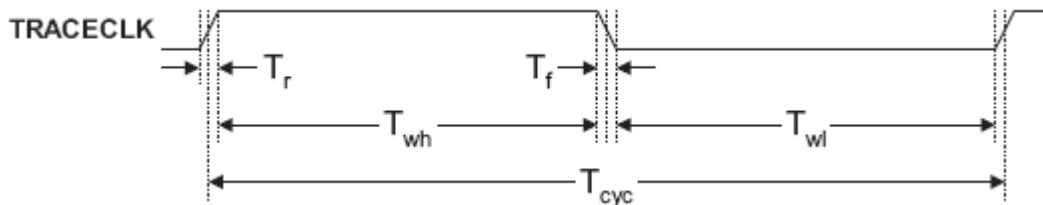
SDRAM CLK and DQS related parameters are being measured from the 50% point—that is, high is defined as 50% of signal value and low is defined as 50% of signal value.

The timing parameters are similar to the ones used in SDRAM data sheets—that is, [Table 38](#) indicates SDRAM requirements. All output signals are driven by the ESDCTL at the negative edge of SDCLK and the parameters are measured at maximum memory frequency.

### 4.3.10 ETM Electrical Specifications

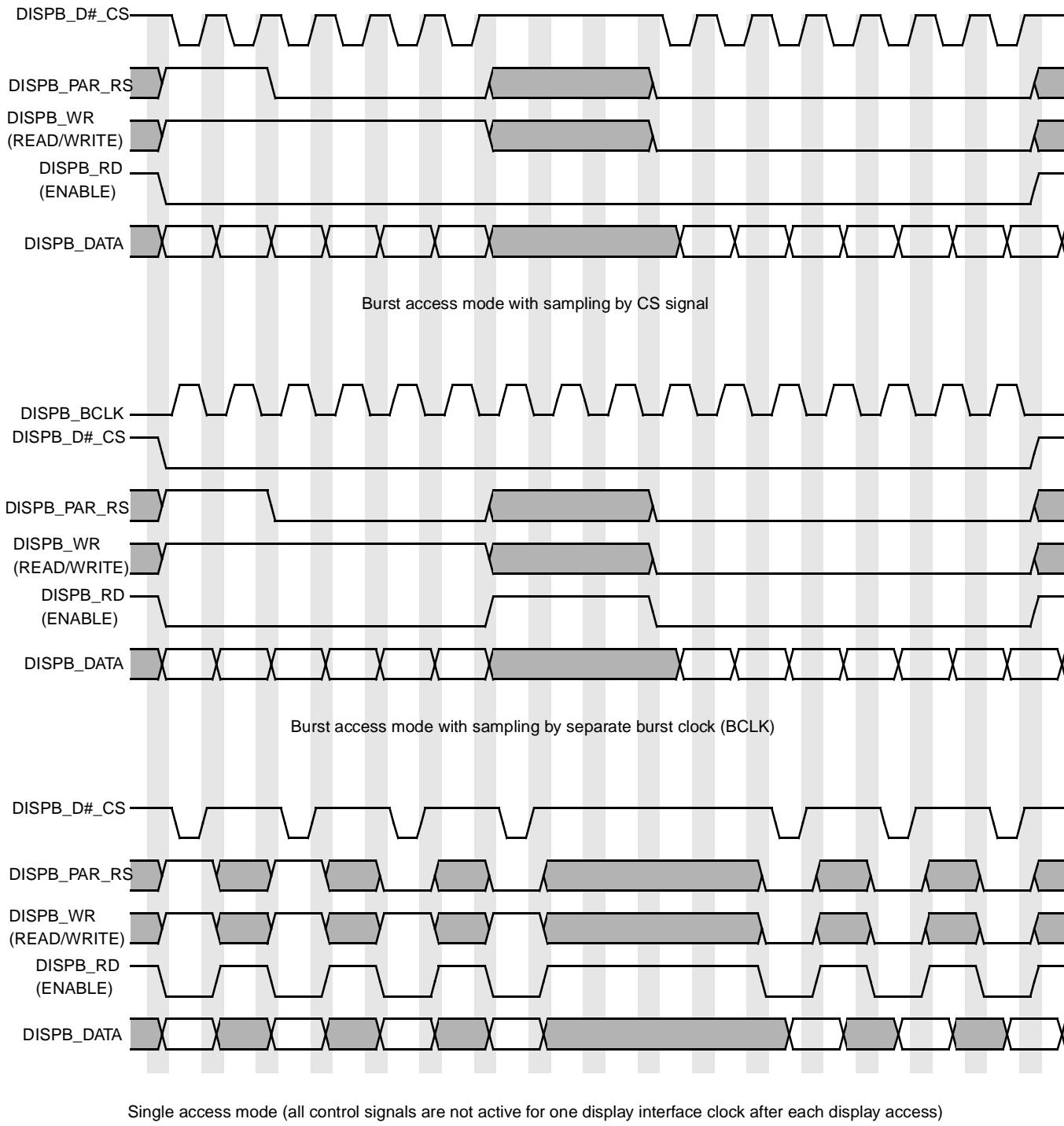
ETM is an ARM protocol. The timing specifications in this section are given as a guide for a TPA that supports TRACECLK frequencies up to 133 MHz.

[Figure 39](#) depicts the TRACECLK timings of ETM, and [Table 39](#) lists the timing parameters.



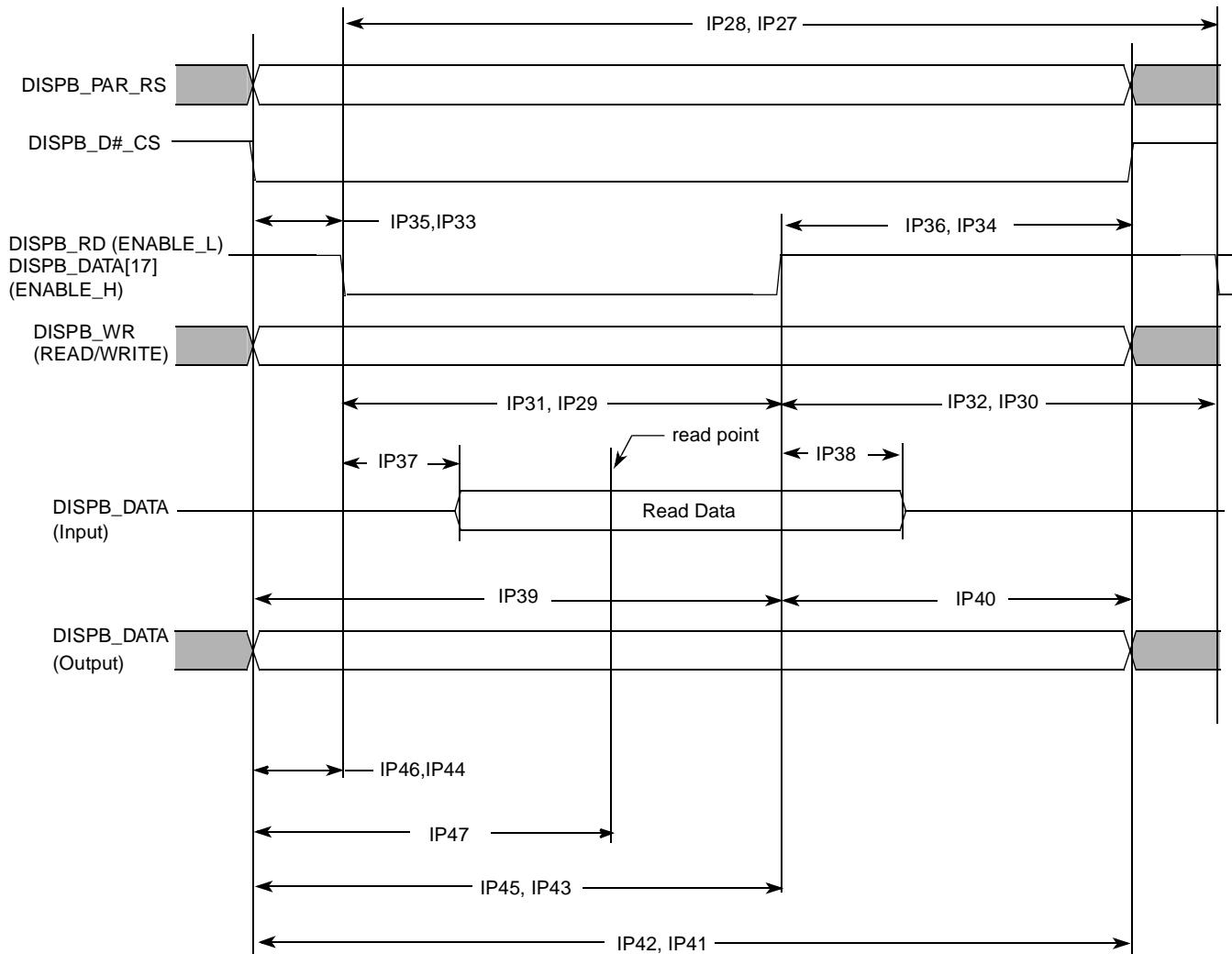
**Figure 39. ETM TRACECLK Timing Diagram**

## Electrical Characteristics



**Figure 53. Asynchronous Parallel System 68k Interface (Type 1) Burst Mode Timing Diagram**

## Electrical Characteristics



**Figure 59. Asynchronous Parallel System 68k Interface (Type 2) Timing Diagram**

**Table 49. Asynchronous Parallel Interface Timing Parameters—Access Level**

ID	Parameter	Symbol	Min.	Typ. <sup>1</sup>	Max.	Units
IP27	Read system cycle time	Tcycr	Tdicpr-1.5	Tdicpr <sup>2</sup>	Tdicpr+1.5	ns
IP28	Write system cycle time	Tcycw	Tdicpw-1.5	Tdicpw <sup>3</sup>	Tdicpw+1.5	ns
IP29	Read low pulse width	Trl	Tdicdr-Tdicur-1.5	Tdicdr <sup>4</sup> -Tdicur <sup>5</sup>	Tdicdr-Tdicur+1.5	ns
IP30	Read high pulse width	Trh	Tdicpr-Tdicdr+Tdicur-1.5	Tdicpr-Tdicdr+Tdicur	Tdicpr-Tdicdr+Tdicur+1.5	ns
IP31	Write low pulse width	Twl	Tdicdw-Tdicuw-1.5	Tdicdw <sup>6</sup> -Tdicuw <sup>7</sup>	Tdicdw-Tdicuw+1.5	ns
IP32	Write high pulse width	Twh	Tdicpw-Tdicdw+Tdicuw-1.5	Tdicpw-Tdicdw+Tdicuw	Tdicpw-Tdicdw+Tdicuw+1.5	ns
IP33	Controls setup time for read	Tdcsr	Tdicur-1.5	Tdicur	—	ns
IP34	Controls hold time for read	Tdchr	Tdicpr-Tdicdr-1.5	Tdicpr-Tdicdr	—	ns
IP35	Controls setup time for write	Tdcsw	Tdicuw-1.5	Tdicuw	—	ns

**Table 49. Asynchronous Parallel Interface Timing Parameters—Access Level (continued)**

ID	Parameter	Symbol	Min.	Typ. <sup>1</sup>	Max.	Units
IP36	Controls hold time for write	Tdchw	Tdicpw–Tdicdw–1.5	Tdicpw–Tdicdw	—	ns
IP37	Slave device data delay <sup>8</sup>	Tracc	0	—	Tdrp <sup>9</sup> –Tlbd <sup>10</sup> –Tdicur–1.5	ns
IP38	Slave device data hold time <sup>8</sup>	Troh	Tdrp–Tlbd–Tdicdr+1.5	—	Tdicpr–Tdicdr–1.5	ns
IP39	Write data setup time	Tds	Tdicdw–1.5	Tdicdw	—	ns
IP40	Write data hold time	Tdh	Tdicpw–Tdicdw–1.5	Tdicpw–Tdicdw	—	ns
IP41	Read period <sup>2</sup>	Tdicpr	Tdicpr–1.5	Tdicpr	Tdicpr+1.5	ns
IP42	Write period <sup>3</sup>	Tdicpw	Tdicpw–1.5	Tdicpw	Tdicpw+1.5	ns
IP43	Read down time <sup>4</sup>	Tdicdr	Tdicdr–1.5	Tdicdr	Tdicdr+1.5	ns
IP44	Read up time <sup>5</sup>	Tdicur	Tdicur–1.5	Tdicur	Tdicur+1.5	ns
IP45	Write down time <sup>6</sup>	Tdicdw	Tdicdw–1.5	Tdicdw	Tdicdw+1.5	ns
IP46	Write up time <sup>7</sup>	Tdicuw	Tdicuw–1.5	Tdicuw	Tdicuw+1.5	ns
IP47	Read time point <sup>9</sup>	Tdrp	Tdrp–1.5	Tdrp	Tdrp+1.5	ns

<sup>1</sup>The exact conditions have not been finalized, but will likely match the current customer requirement for their specific display. These conditions may be device specific.

<sup>2</sup> Display interface clock period value for read:

$$T_{dicpr} = T_{HSP\_CLK} \cdot \text{ceil}\left[\frac{\text{DISP\# IF CLK PER RD}}{HSP\_CLK\_PERIOD}\right]$$

<sup>3</sup> Display interface clock period value for write:

$$T_{dicpw} = T_{HSP\_CLK} \cdot \text{ceil}\left[\frac{\text{DISP\# IF CLK PER WR}}{HSP\_CLK\_PERIOD}\right]$$

<sup>4</sup> Display interface clock down time for read:

$$T_{dicdr} = \frac{1}{2}T_{HSP\_CLK} \cdot \text{ceil}\left[\frac{2 \cdot \text{DISP\# IF CLK DOWN RD}}{HSP\_CLK\_PERIOD}\right]$$

<sup>5</sup> Display interface clock up time for read:

$$T_{dicur} = \frac{1}{2}T_{HSP\_CLK} \cdot \text{ceil}\left[\frac{2 \cdot \text{DISP\# IF CLK UP RD}}{HSP\_CLK\_PERIOD}\right]$$

<sup>6</sup> Display interface clock down time for write:

$$T_{dicdw} = \frac{1}{2}T_{HSP\_CLK} \cdot \text{ceil}\left[\frac{2 \cdot \text{DISP\# IF CLK DOWN WR}}{HSP\_CLK\_PERIOD}\right]$$

<sup>7</sup> Display interface clock up time for write:

$$T_{dicuw} = \frac{1}{2}T_{HSP\_CLK} \cdot \text{ceil}\left[\frac{2 \cdot \text{DISP\# IF CLK UP WR}}{HSP\_CLK\_PERIOD}\right]$$

<sup>8</sup> This parameter is a requirement to the display connected to the IPU

<sup>9</sup> Data read point

$$T_{drp} = T_{HSP\_CLK} \cdot \text{ceil}\left[\frac{\text{DISP\# READ EN}}{HSP\_CLK\_PERIOD}\right]$$

<sup>10</sup> Loopback delay Tlbd is the cumulative propagation delay of read controls and read data. It includes an IPU output delay, a device-level output delay, board delays, a device-level input delay, an IPU input delay. This value is device specific.

## Electrical Characteristics

### 4.3.15.5.4 Serial Interfaces, Electrical Characteristics

Figure 64 depicts timing of the serial interface. Table 50 lists the timing parameters at display access level.

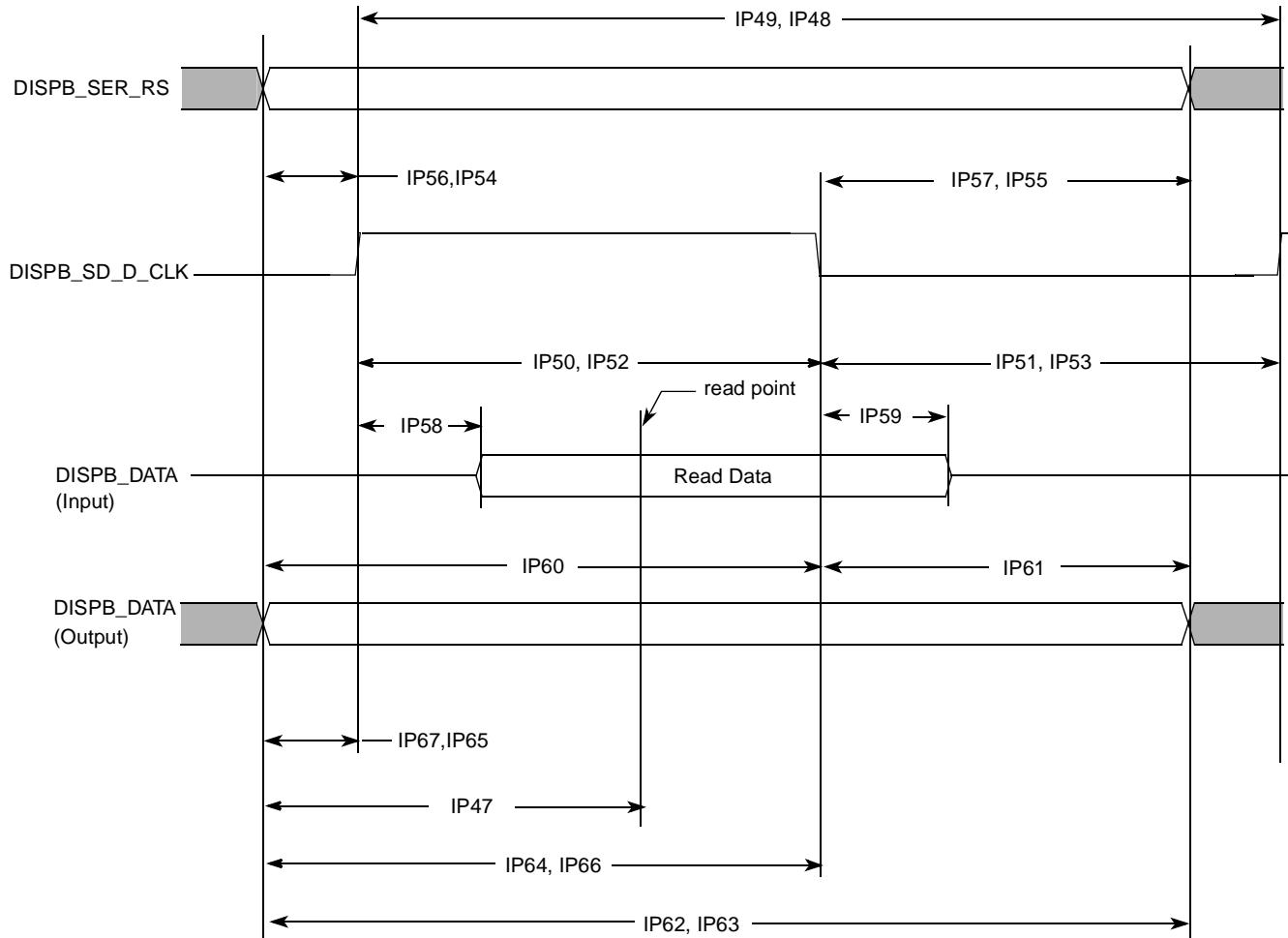


Figure 64. Asynchronous Serial Interface Timing Diagram

Table 50. Asynchronous Serial Interface Timing Parameters—Access Level

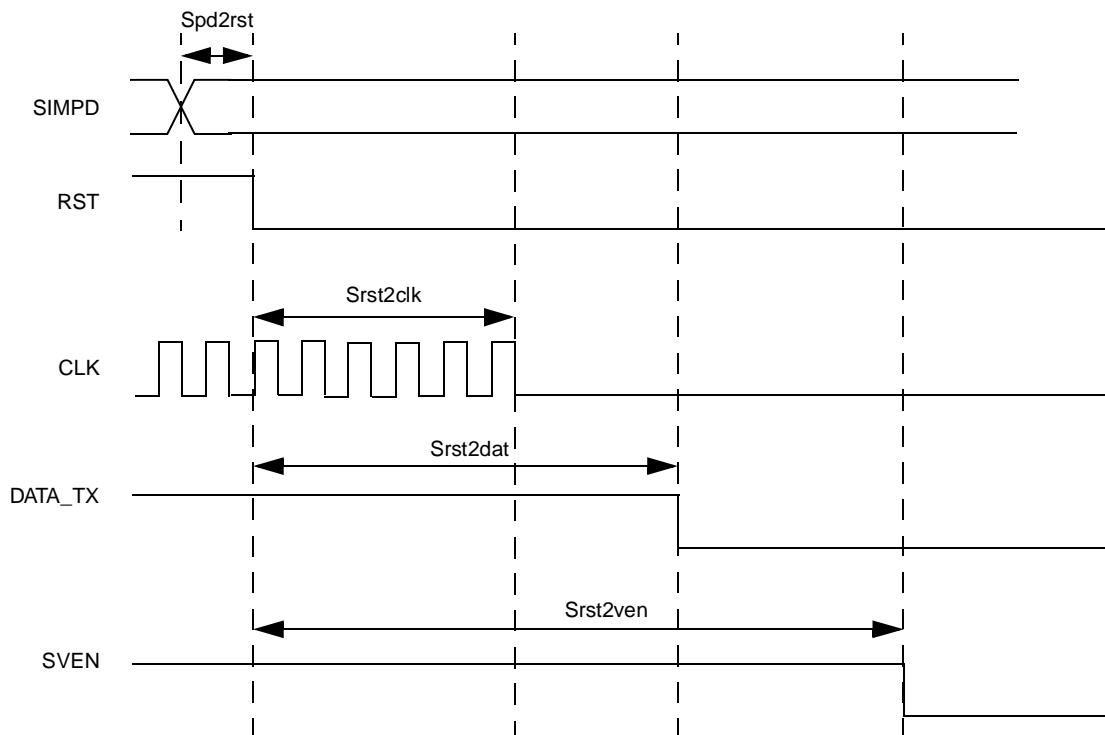
ID	Parameter	Symbol	Min.	Typ. <sup>1</sup>	Max.	Units
IP48	Read system cycle time	Tcycr	Tdicpr-1.5	Tdicpr <sup>2</sup>	Tdicpr+1.5	ns
IP49	Write system cycle time	Tcycw	Tdicpw-1.5	Tdicpw <sup>3</sup>	Tdicpw+1.5	ns
IP50	Read clock low pulse width	Trl	Tdicdr-Tdicur-1.5	Tdicdr <sup>4</sup> -Tdicur <sup>5</sup>	Tdicdr-Tdicur+1.5	ns
IP51	Read clock high pulse width	Trh	Tdicpr-Tdicdr+Tdicur-1.5	Tdicpr-Tdicdr+Tdicur	Tdicpr-Tdicdr+Tdicur+1.5	ns
IP52	Write clock low pulse width	Twl	Tdicdw-Tdicuw-1.5	Tdicdw <sup>6</sup> -Tdicuw <sup>7</sup>	Tdicdw-Tdicuw+1.5	ns
IP53	Write clock high pulse width	Twh	Tdicpw-Tdicdw+Tdicuw-1.5	Tdicpw-Tdicdw+Tdicuw	Tdicpw-Tdicdw+Tdicuw+1.5	ns
IP54	Controls setup time for read	Tdcsr	Tdicur-1.5	Tdicur	—	ns
IP55	Controls hold time for read	Tdchr	Tdicpr-Tdicdr-1.5	Tdicpr-Tdicdr	—	ns

### 4.3.20.3 Power Down Sequence

Power down sequence for SIM interface is as follows:

1. SIMPD port detects the removal of the SIM Card
2. RST goes Low
3. CLK goes Low
4. TX goes Low
5. VEN goes Low

Each of this steps is done in one CKIL period (usually 32 kHz). Power down can be started because of a SIM Card removal detection or launched by the processor. [Figure 75](#) and [Table 57](#) show the usual timing requirements for this sequence, with  $F_{CKIL}$  = CKIL frequency value.



**Figure 75. SmartCard Interface Power Down AC Timing**

**Table 57. Timing Requirements for Power Down Sequence**

Num	Description	Symbol	Min	Max	Unit
1	SIM reset to SIM clock stop	$S_{rst2clk}$	$0.9*1/F_{CKIL}$	0.8	$\mu s$
2	SIM reset to SIM TX data low	$S_{rst2dat}$	$1.8*1/F_{CKIL}$	1.2	$\mu s$
3	SIM reset to SIM Voltage Enable Low	$S_{rst2ven}$	$2.7*1/F_{CKIL}$	1.8	$\mu s$
4	SIM Presence Detect to SIM reset Low	$S_{pd2rst}$	$0.9*1/F_{CKIL}$	25	ns

#### 4.3.22.2 SSI Receiver Timing with Internal Clock

Figure 81 depicts the SSI receiver timing with internal clock, and Table 60 lists the timing parameters.

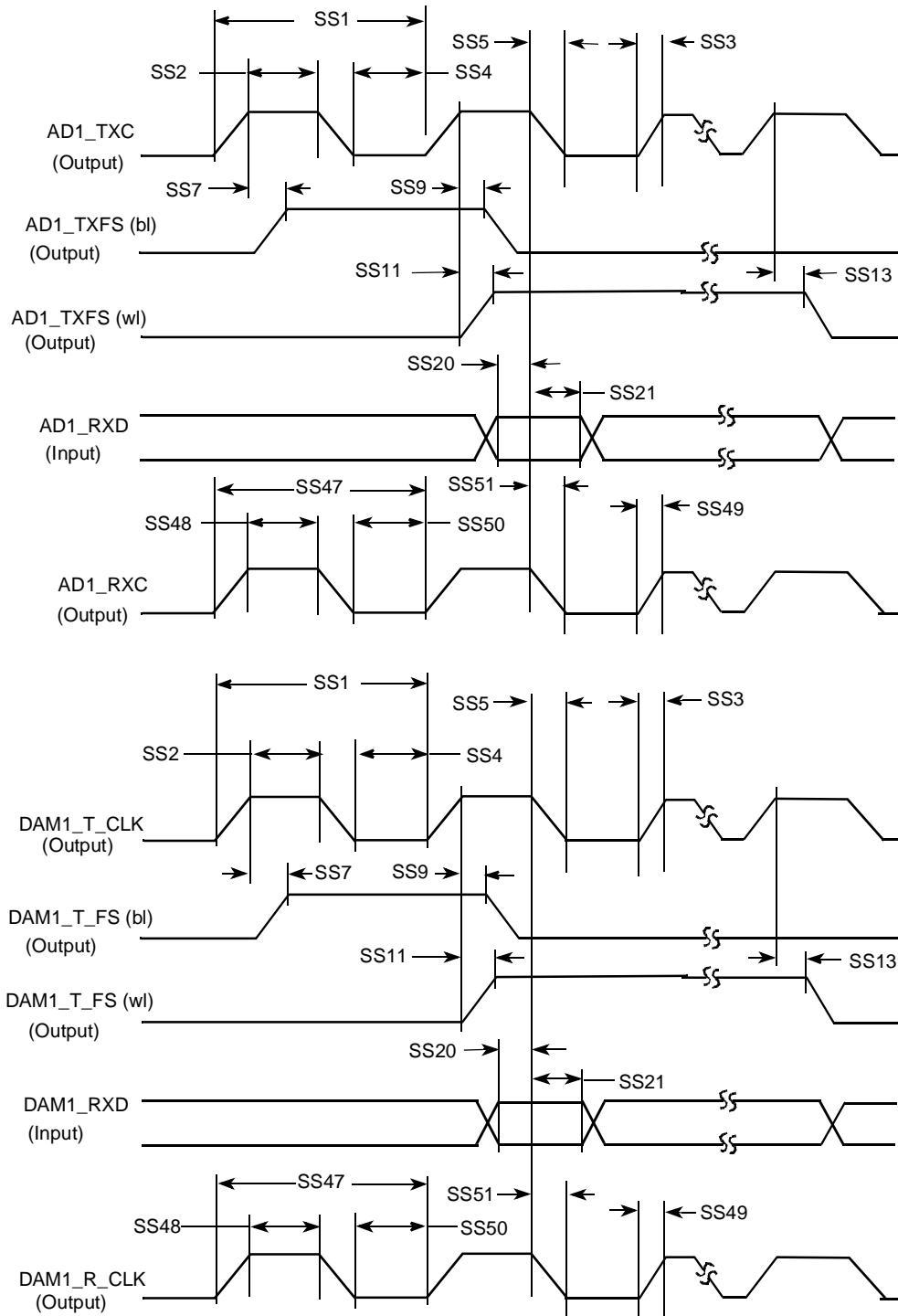


Figure 81. SSI Receiver with Internal Clock Timing Diagram

## Electrical Characteristics

**Table 61. SSI Transmitter with External Clock Timing Parameters**

ID	Parameter	Min	Max	Unit
External Clock Operation				
SS22	(Tx/Rx) CK clock period	81.4	—	ns
SS23	(Tx/Rx) CK clock high period	36.0	—	ns
SS24	(Tx/Rx) CK clock rise time	—	6.0	ns
SS25	(Tx/Rx) CK clock low period	36.0	—	ns
SS26	(Tx/Rx) CK clock fall time	—	6.0	ns
SS27	(Tx) CK high to FS (bl) high	-10.0	15.0	ns
SS29	(Tx) CK high to FS (bl) low	10.0	—	ns
SS31	(Tx) CK high to FS (wl) high	-10.0	15.0	ns
SS33	(Tx) CK high to FS (wl) low	10.0	—	ns
SS37	(Tx) CK high to STXD valid from high impedance	—	15.0	ns
SS38	(Tx) CK high to STXD high/low	—	15.0	ns
SS39	(Tx) CK high to STXD high impedance	—	15.0	ns
Synchronous External Clock Operation				
SS44	SRXD setup before (Tx) CK falling	10.0	—	ns
SS45	SRXD hold after (Tx) CK falling	2.0	—	ns
SS46	SRXD rise/fall time	—	6.0	ns

## 5 Package Information and Pinout

This section includes the contact assignment information and mechanical package drawing for the MCIMX31.

### 5.1 MAPBGA Production Package—457 14 x 14 mm, 0.5 mm Pitch

This section contains the outline drawing, signal assignment map (see [Section 7, “Revision History,”](#) [Table 69](#) for the 0.5 mm 14 × 14 MAPBGA signal assignments), and MAPBGA ground/power ID by ball grid location for the 457 14 x 14 mm, 0.5 mm pitch package.

#### 5.1.1 Production Package Outline Drawing—14 x 14 mm 0.5 mm

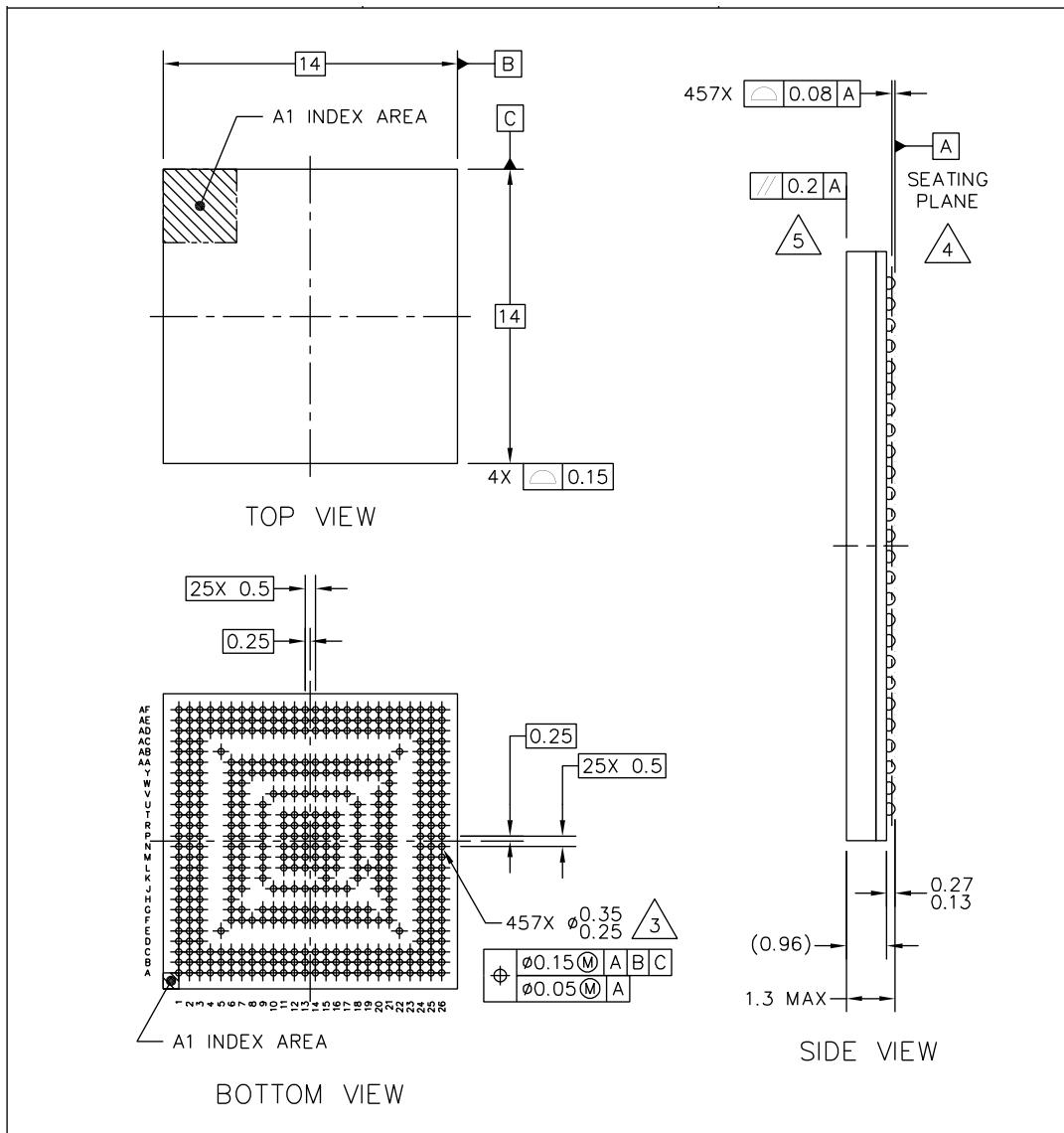


Figure 85. Production Package: Case 1581—0.5 mm Pitch

## 5.1.2 MAPBGA Signal Assignment—14 × 14 mm 0.5 mm

See [Section 7, “Revision History,”](#) [Figure 69](#) for the 0.5 mm 14 × 14 MAPBGA signal assignments.

## 5.1.3 Connection Tables—14 × 14 mm 0.5 mm

[Table 64](#) shows the device connection list for power and ground, alpha-sorted. [Table 65](#) shows the device connection list for signals.

### 5.1.3.1 Ground and Power ID Locations—14 × 14 mm 0.5 mm

**Table 64. 14 × 14 MAPBGA Ground/Power ID by Ball Grid Location**

GND/PWR ID	Ball Location
FGND	AB24
FUSE_VDD	AC24
FVCC	AA24
GND	A1, A2, A25, A26, B1, B2, B25, B26, C1, C2, C24, C25, C26, D1, D25, E22, E24, F21, L12, M11, M12, M13, M14, M15, M16, N12, N13, N14, N15, N16, P12, P13, P14, P15, P16, R12, R13, R14, R15, R16, T12, T13, V17, AC2, AC26, AD1, AD2, AD24, AD25, AD26, AE1, AE2, AE24, AE25, AE26, AF1, AF2, AF25, AF26
IOQVDD	Y6
MGND	T15
MVCC	V15
NVCC1	G19, G21, K18
NVCC2	Y17, Y18, Y19, Y20
NVCC3	L9, M9, N11
NVCC4	L18, L19
NVCC5	E5, F6, G7
NVCC6	J15, J16, K15
NVCC7	N18, P18, R18, T18
NVCC8	J12, J13
NVCC9	J17
NVCC10	P9, P11, R11, T11
NVCC21	Y14, Y15, Y16
NVCC22	W7, Y7, Y8, Y9, Y10, Y11, Y12, Y13, AA6
QVCC	J14, L13, L14, L15, L16, M18, U18, V10, V11, V12, V13
QVCC1	J10, J11, K9, L11
QVCC4	N9, R9, T9, U9
SGND	T14
SVCC	V14
UVCC	V16
UGND	T16

### 5.1.3.2 BGA Signal ID by Ball Grid Location–14 x 14 0.5 mm

Table 65 shows the device connection list for signals only, alpha-sorted by signal identification.

**Table 65. 14 x 14 BGA Signal ID by Ball Grid Location**

Signal ID	Ball Location	Signal ID	Ball Location
A0	AD6	CKIL	H21
A1	AF5	CLKO	C23
A10	AF18	CLKSS	G26
A11	AC3	COMPARE	G18
A12	AD3	CONTRAST	R24
A13	AD4	CS0	AE23
A14	AF17	CS1	AF23
A15	AF16	CS2	AE21
A16	AF15	CS3	AD22
A17	AF14	CS4	AF24
A18	AF13	CS5	AF22
A19	AF12	CSI_D10	M24
A2	AB5	CSI_D11	L26
A20	AF11	CSI_D12	M21
A21	AF10	CSI_D13	M25
A22	AF9	CSI_D14	M20
A23	AF8	CSI_D15	M26
A24	AF7	CSI_D4	L21
A25	AF6	CSI_D5	K25
A3	AE4	CSI_D6	L24
A4	AA3	CSI_D7	K26
A5	AF4	CSI_D8	L20
A6	AB3	CSI_D9	L25
A7	AE3	CSI_HSYNC	K20
A8	AD5	CSI_MCLK	K24
A9	AF3	CSI_PIXCLK	J26
ATA_CS0	J6	CSI_VSYNC	J25
ATA_CS1	F2	CSPI1_MISO	P7
ATA_DIOR	E2	CSPI1_MOSI	P2
ATA_DIOW	H6	CSPI1_SCLK	N2
ATA_DMACK	F1	CSPI1_SPI_RDY	N3
ATA_RESET	H3	CSPI1_SS0	P3
BATT_LINE	F7	CSPI1_SS1	P1
BCLK	AB26	CSPI1_SS2	P6
BOOT_MODE0	F20	CSPI2_MISO	A4
BOOT_MODE1	C21	CSPI2_MOSI	E3
BOOT_MODE2	D24	CSPI2_SCLK	C7
BOOT_MODE3	C22	CSPI2_SPI_RDY	B6
BOOT_MODE4	D26	CSPI2_SS0	B5
CAPTURE	A22	CSPI2_SS1	C6
CAS	AD20	CSPI2_SS2	A5
CE_CONTROL	A14	CSPI3_MISO	G3
CKIH	F24	CSPI3_MOSI	D2

**Table 67. 19 x 19 BGA No Connects<sup>1</sup>**

Signal	Ball Location
NC	N7
NC	P7
NC	U21

<sup>1</sup> These contacts are not used and must be floated by the user.

### 5.2.3.2 BGA Signal ID by Ball Grid Location—19 x 19 0.8 mm

**Table 68. 19 x 19 BGA Signal ID by Ball Grid Location**

Signal ID	Ball Location	Signal ID	Ball Location
A0	Y6	CKIL	E21
A1	AC5	CLKO	C20
A10	V15	CLKSS	H17
A11	AB3	COMPARE	A20
A12	AA3	CONTRAST	N21
A13	Y3	CS0	U17
A14	Y15	CS1	Y22
A15	Y14	CS2	Y18
A16	V14	CS3	Y19
A17	Y13	CS4	Y20
A18	V13	CS5	AA21
A19	Y12	CSI_D10	K21
A2	AB5	CSI_D11	K22
A20	V12	CSI_D12	K23
A21	Y11	CSI_D13	L20
A22	V11	CSI_D14	L18
A23	Y10	CSI_D15	L21
A24	Y9	CSI_D4	J20
A25	Y8	CSI_D5	J21
A3	AA5	CSI_D6	L17
A4	Y5	CSI_D7	J22
A5	AC4	CSI_D8	J23
A6	AB4	CSI_D9	K20
A7	AA4	CSI_HSYNC	H22
A8	Y4	CSI_MCLK	H20
A9	AC3	CSI_PIXCLK	H23
ATA_CS0	E1	CSI_VSYNC	H21
ATA_CS1	G4	CSPI1_MISO	N2
ATA_DIOR	E3	CSPI1_MOSI	N1
ATA_DIOW	H6	CSPI1_SCLK	M4
ATA_DMACK	E2	CSPI1_SPI_RDY	M1
ATA_RESET	F3	CSPI1_SS0	M2
BATT_LINE	F6	CSPI1_SS1	N6
BCLK	W20	CSPI1_SS2	M3

## 5.3 Ball Maps

**Table 69. Ball Map—14 x 14 0.5 mm Pitch**

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26			
A	GND	GND	SFS5	CSP12_MISO	CSP12_SS2	USBOT_G_DAT_A7	USBOT_G_NXT_A3	USBOT_BYP	RXD1	DSR_D_CE1	DSR_D_TE1	RXD2	CE_CO_NTROL	KEY_R_OW3	KEY_R_OW7	KEY_C_OL3	KEY_C_OL7	TDO	SJC_MOD	SVEN0	CAPTURE	GPIO1_6	WATCHDOG_RST	GND	GND	A			
B	GND	GND	STXD4	SRXD5	CSP12_SS0	USBOT_G_DAT_A5	USBOT_G_DIR	USBOT_P_WB	CTS1	DCD_D_CE1	DCD_D_TE1	RTS2	KEY_R_OW1	KEY_R_OW5	KEY_C_OL1	KEY_C_OL5	TCK	TRSTB	SRX0	SCLK0	GPIO1_1	GPIO1_5	GND	GND	B				
C	GND	GND	SRXD4	SCK4	STXD5	CSP12_SS1	CSP12_SCLK	USBOT_G_DAT_A4	USBOT_G_STP	USBOT_O_C	DTR_D_CE1	DTR_D_TE1	TXD2	KEY_R_OW2	KEY_C_OL0	KEY_C_OL4	RTCK	DE	SRST0	GPIO1_2	BOOT_MODE1	BOOT_MODE3	CLK0	GND	GND	GND	C		
D	GND	CSP13_MOSI	SCK5																						BOOT_MODE2	GND	BOOT_MODE4	D	
E	CSP13_SCLK	ATA_DI_OR	CSP12_MOSI		NVCC5																				GND	DVFS0	POWER_FAIL	E	
F	ATA_D_MACK	ATA_C_S1	SFS4			NVCC5	BATT_L_INE	USBOT_G_DAT_A6	USBOT_G_DAT_A0	RXD1	RI_DC_E1	DTR_D_CE2	KEY_R_OW0	KEY_R_OW6	KEY_C_OL6	TDI	STX0	GPIO1_0	GPIO1_4	BOOT_MODE0	GND			CKIH	GPIO1_3	VSTBY	F		
G	PWMO	PC_RW	CSP13_MISO			CSP13_SPLR_DY	NVCC5		USBOT_G_CLK	USBOT_G_DAT_A2	RTS1	RI_DT_E1	CTS2	KEY_R_OW4	KEY_C_OL2	TMS	SIMPD0	COMPARE	NVCC1					DVFS1	VPG0	CLKSS	G		
H	PC_RS	PC_BV_T	ATA_R_D1	ESET		ATA_DI_OW																CKIL			POR	I2C_DA_T	GPIO3_1	H	
J	PC_VS_1	PC_RE_ADY	IOIS16			ATA_C_S0	PC_PO_E		QVCC1	QVCC1	NVCC8	NVCC8	QVCC	NVCC6	NVCC6	NVCC6	NVCC9		VPG1	RESET_IN				I2C_CL_K	CSI_VSYNC	CSI_PIX_CLK	J		
K	PC_CD_2	SD1_D_ATA3	PC_PW_RON			PC_BV_D2	PC_VS_2	QVCC1						NVCC6		NVCC1		CSI_H_SYNC_0	GPIO3_0				CSI_MC_LK	CSI_D5	CSI_D7	K			
L	SD1_D_ATA1	SD1_C_SD1_D_MD	SD1_D_ATA2			PC_WA_IT	PC_CD_1	NVCC3		QVCC1	GND	QVCC	QVCC	QVCC	QVCC	QVCC	NVCC4	NVCC4	CSI_D8	CSI_D4				CSI_D6	CSI_D9	CSI_D1_1	L		
M	USBH2_DATA0	USBH2_STP	USBH2_DATA1			SD1_D_ATA0	SD1_C_LK	NVCC3		GND	GND	GND	GND	GND	GND	GND	QVCC		CSI_D1_4	CSI_D1_2				CSI_D1_0	CSI_D1_3	CSI_D1_5	M		
N	USBH2_CLK	CSP11_SCLK	CSP11_SPI_RDY			USBH2_NXT_DIR	USBH2	QVCC4	NVCC3	GND	GND	GND	GND	GND	GND	GND	NVCC7		SD_D_FPSHIFT					VSYNC	HSYNC	DRDY0	N		
P	CSP11_SS1	CSP11_MOSI	CSP11_SS0			CSP11_SS2	CSP11_MISO	NVCC1_0	NVCC1_0	GND	GND	GND	GND	GND	GND	GND	NVCC7		READ	LCS1				SD_D_CLK_O	SD_D_I	LCS0	P		
R	STXD3	SCK3	SRXD3			SFS3	SRXD6	QVCC4	NVCC1_0	GND	GND	GND	GND	GND	GND	GND	NVCC7		D3_CL_S	PAR_RS				CONTRAST	WRITE	VSYNC_3	R		
T	STXD6	SCK6	SFS6			NFCE	NFWF	QVCC4	NVCC1_0	GND	GND	SGND	MGND	UGND		NVCC7		LD4	LD2				LD0	SER_RS	D3_REV	T			
U	NFRB	NFWF	NFCLE			D15	D11	QVCC4								QVCC		TTM_PAD	LD8				LD6	D3_SPL	LD1	U			
V	NFALE	NFRE	D13			D9	D5	QVCC	QVCC	QVCC	QVCC	SVCC	MVCC	UVCC	GND			LD17	LD13				LD10	LD3	LD5	V			
W	D14	D12	D7			D3	NVCC2_2																EB0			LD15	LD7	LD9	W
Y	D10	D8	D1			IOQVD_D	NVCC2_2	NVCC2_2	NVCC2_2	NVCC2_2	NVCC2_2	NVCC2_2	NVCC2_1	NVCC2_1	NVCC2_1	NVCC2_1	NVCC2_1	NVCC2_1	NVCC2_1	NVCC2_1	M_GRAINT			EB1	LD11	LD12	Y		
AA	D6	D4	A4			NVCC2_2	SD31	SD28	SD27	SD23	SD21	SD18	SD16	SD13	SD9	SD7	SD5	SD3	SD2	DQM2	SDCLK				FVCC	LD14	LD16	AA	
AB	D2	D0	A6			A2																		RW		FGND	OE	BCLK	AB
AC	MA10	GND	A11																					FUSE_VDD	M_REQUEST	GND	AC		
AD	GND	GND	A12	A13	A8	A0	SDBA0	SDQS3	SD29	SD25	SDQS2	SD17	SD15	SD12	SD8	SDQSO	SD4	SD0	DQM1	CAS_0	SDCKE	CS3	ECB	GND	GND	GND	AD		
AE	GND	GND	A7	A3	SDBA1	SD30	SD26	SD24	SD22	SD20	SD19	SDQS1	SD14	SD11	SD10	SD6	SD1	DQM3	DQM0	SDCLK	CS2	LBA	CS0	GND	GND	GND	AE		
AF	GND	GND	A9	A5	A1	A25	A24	A23	A22	A21	A20	A19	A18	A17	A16	A15	A14	A10	RAS	SDWE	SDCKE_1	CS5	CS1	CS4	GND	GND	GND	AF	